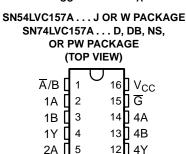
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FEATURES

- Operate From 1.65 V to 3.6 V
- Specified From -40°C to 85°C, -40°C to 125°C, and -55°C to 125°C
- Inputs Accept Voltages to 5.5 V
- Max t_{pd} of 5.2 ns at 3.3 V
- Typical V_{OLP} (Output Ground Bounce)
 < 0.8 V at V_{CC} = 3.3 V, T_A = 25°C
- Typical V_{OHV} (Output V_{OH} Undershoot)
 2 V at V_{CC} = 3.3 V, T_A = 25°C

- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)



2B

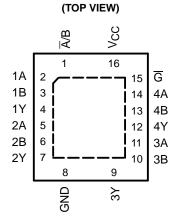
2Y

GND

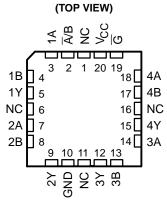
6

7

8



SN74LVC157A...RGY PACKAGE



SN54LVC157A...FK PACKAGE

NC - No internal connection

DESCRIPTION/ORDERING INFORMATION

11**∏** 3A

10**∏** 3B

9 T 3Y

These quadruple 2-line to 1-line data selectors/multiplexers are designed for 1.65-V to 3.6-V V_{CC} operation.

The 'LVC157A devices feature a common strobe (\overline{G}) input. When \overline{G} is high, all outputs are low. When \overline{G} is low, a 4-bit word is selected from one of two sources and is routed to the four outputs. The devices provide true data.

ORDERING INFORMATION

T _A	P.A	CKAGE ⁽¹⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 85°C	QFN – RGY	Reel of 1000	SN74LVC157ARGYR	LC157A
		Tube of 40	SN74LVC157AD	
	SOIC - D	Reel of 2500	SN74LVC157ADR	LVC157A
		Reel of 250	SN74LVC157ADT	
–40°C to 125°C	SOP - NS	Reel of 2000	SN74LVC157ANSR	LVC157A
-40 C to 125 C	SSOP - DB	Reel of 2000	SN74LVC157ADBR	LC157A
		Tube of 90	SN74LVC157APW	
	TSSOP - PW	Reel of 2000	SN74LVC157APWR	LC157A
		Reel of 250	SN74LVC157APWT	
	CDIP – J	Tube of 25	SNJ54LVC157AJ	SNJ54LVC157AJ
–55°C to 125°C	CFP – W	Tube of 150	SNJ54LVC157AW	SNJ54LVC157AW
	LCCC - FK	Tube of 55	SNJ54LVC157AFK	SNJ54LVC157AFK

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



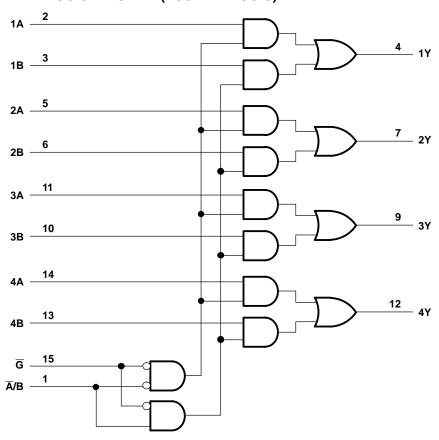
DESCRIPTION/ORDERING INFORMATION (CONTINUED)

Inputs can be driven from either 3.3-V or 5-V devices. This feature allows the use of these devices as translators in a mixed 3.3-V/5-V system environment.

FUNCTION TABLE

	INP	UTS		OUTPUT	
G	Ā/B	Α	В	Υ	
Н	Х	Х	Х	L	
L	L	L	X	L	
L	L	Н	X	Н	
L	Н	X	L	L	
L	Н	X	Н	Н	

LOGIC DIAGRAM (POSITIVE LOGIC)



Pin numbers shown are for the D, DB, J, NS, PW, RGY, and W packages.



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Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

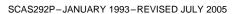
			MIN	MAX	UNIT	
V _{CC}	Supply voltage range		-0.5	6.5	V	
V _I	Input voltage range ⁽²⁾		-0.5	6.5	V	
Vo	Output voltage range ⁽²⁾⁽³⁾		-0.5	V _{CC} + 0.5	V	
I _{IK}	Input clamp current	V _I < 0		-50	mA	
I _{OK}	Output clamp current	V _O < 0		-50	mA	
Io	Continuous output current			±50	mA	
	Continuous current through V _{CC} or GND			±100	mA	
		D package ⁽⁴⁾		73		
		DB package ⁽⁴⁾		82		
θ_{JA}	Package thermal impedance	NS package ⁽⁴⁾		64	°C/W	
		PW package ⁽⁴⁾		108		
		RGY package ⁽⁵⁾		39		
T _{stg}	Storage temperature range	,	-65	150	°C	
P _{tot}	Power dissipation ⁽⁶⁾⁽⁷⁾	$T_A = -40^{\circ}C$ to 125°C		500	mW	

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
- The value of V_{CC} is provided in the recommended operating conditions table.
- The package thermal impedance is calculated in accordance with JESD 51-7.
- The package thermal impedance is calculated in accordance with JESD 51-5.
- For the D package, above 70°C the value of P_{tot} derates linearly with 8 mW/K. For the DB, NS, and PW packages, above 60°C the value of P_{tot} derates linearly with 5.5 mW/K.

Recommended Operating Conditions⁽¹⁾

			SN54LV	C157A	UNIT
			-55 TO	125°C	
			MIN	MAX	
V	Cupply voltage	Operating	2	3.6	V
V _{CC}	Supply voltage	Data retention only	1.5		
V_{IH}	High-level input voltage	V _{CC} = 2.7 V to 3.6 V	2		V
V_{IL}	Low-level input voltage	V _{CC} = 2.7 V to 3.6 V		0.8	V
VI	Input voltage	·	0	5.5	V
Vo	Output voltage		0	V_{CC}	V
	High level cutout current	V _{CC} = 2.7 V		-12	A
I _{OH}	High-level output current	V _{CC} = 3 V		-24	mA
	Low lovel output ourrent	V _{CC} = 2.7 V		12	A
I _{OL}	Low-level output current	V _{CC} = 3 V		24	mA

All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.





Recommended Operating Conditions(1)

					SN74L	/C157A				
			T _A =	25°C	-40 TO	O 85°C	-40 TO 125°C		UNIT	
			MIN	MAX	MIN	MAX	MIN	MAX		
V	Cupply voltage	Operating	1.65	3.6	1.65	3.6	1.65	3.6	V	
V_{CC}	Supply voltage	Data retention only	1.5		1.5		1.5		V	
		V _{CC} = 1.65 V to 1.95 V	$0.65 \times V_{CC}$		$0.65 \times V_{CC}$		$0.65 \times V_{CC}$			
V_{IH}	High-level input voltage	V _{CC} = 2.3 V to 2.7 V	1.7		1.7		1.7		V	
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2		2		2			
		V _{CC} = 1.65 V to 1.95 V		$0.35 \times V_{CC}$		$0.35 \times V_{CC}$		$0.35 \times V_{CC}$		
V_{IL}	Low-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7		0.7		0.7	V	
		V _{CC} = 2.7 V to 3.6 V		0.8		0.8		0.8		
VI	Input voltage		0	5.5	0	5.5	0	5.5	V	
Vo	Output voltage		0	V _{CC}	0	V _{CC}	0	V _{CC}	V	
		V _{CC} = 1.65 V		-4		-4		-4		
	High-level output	V _{CC} = 2.3 V		-8		-8		-8		
I _{OH}	current	V _{CC} = 2.7 V		-12		-12		-12	mA	
		V _{CC} = 3 V		-24		-24		-24		
		V _{CC} = 1.65 V		4		4		4		
	Low-level output	V _{CC} = 2.3 V		8		8		8	mA	
l _{OL}	current	V _{CC} = 2.7 V		12		12		12	mA	
	_	V _{CC} = 3 V		24		24		24		
Δt/Δν	Input transition rise	e or fall rate		10		10		10	ns/V	

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

					SN54LVC1	57A			
PA	RAMETER	TEST CONDITIONS		V _{cc}	-55 TO 12	UNIT			
					MIN	MAX			
		$I_{OH} = -100 \mu A$		2.7 V to 3.6 V	V _{CC} - 0.2				
.,		10 10	2.7 V	2.2		.,			
V _{OH}		$I_{OH} = -12 \text{ mA}$		3 V	2.4		V		
		I _{OH} = -24 mA	3 V	2.2					
		I _{OL} = 100 μA	2.7 V to 3.6 V		0.2				
V_{OL}		I _{OL} = 12 mA	2.7 V		0.4	V			
		I _{OL} = 24 mA	3 V		0.55				
I_{\parallel}	All inputs	V _I = 5.5 V or GND		3.6 V		±5	μΑ		
I_{CC}		$V_I = V_{CC}$ or GND	I _O = 0	3.6 V		10	μΑ		
ΔI_{CC}		One input at V_{CC} – 0.6 V, Other inputs at V_{CC} or GNI)	2.7 V to 3.6 V		500	μΑ		



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Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

				SN74LVC157A								
PARAMETER	TEST CONDI	TEST CONDITIONS		T _A	= 25°C		-40 TO 8	35°C	-40 TO 1	25°C	UNIT	
				MIN	TYP	MAX	MIN	MAX	MIN	MAX		
	$I_{OH} = -100 \mu A$		1.65 V to 3.6 V	V _{CC} - 0.2			V _{CC} - 0.2		V _{CC} - 0.3			
	$I_{OH} = -4 \text{ mA}$		1.65 V	1.29			1.2		1.05			
V	$I_{OH} = -8 \text{ mA}$		2.3 V	1.9			1.7		1.55		V	
V _{OH}	= 12 mΛ		2.7 V	2.2			2.2		2.05		V	
	$I_{OH} = -12 \text{ mA}$		3 V	2.4			2.4		2.25			
	I _{OH} = -24 mA		3 V	2.3			2.2		2			
	$I_{OL} = 100 \mu A$		1.65 V to 3.6 V			0.1		0.2		0.3		
	I _{OL} = 4 mA		1.65 V			0.24		0.45		0.6		
V _{OL}	I _{OL} = 8 mA		2.3 V			0.3		0.7		0.75	V	
	I _{OL} = 12 mA		2.7 V			0.4		0.4		0.6		
	$I_{OL} = 24 \text{ mA}$		3 V			0.55		0.55		0.8		
I _I All inputs	V _I = 5.5 V or GND)	3.6 V			±1		±5		±20	μΑ	
I _{CC}	$V_I = V_{CC}$ or GND	I _O = 0	3.6 V			1		10		40	μΑ	
ΔI_{CC}	One input at V _{CC} Other inputs at V _C	– 0.6 V, _{CC} or GND	2.7 V to 3.6 V			500		500		5000	μΑ	
C _i	$V_I = V_{CC}$ or GND		3.3 V		5						pF	

Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

				SN54LV	C157A			
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC}	–55 TO 125°C		UNIT		
	(31)	(551.51)		(551151)		MIN	MAX	
A or B		2.7 V		6.2				
	AOIB	Y	3.3 V ± 0.3 V	0.8	5.4	ns		
	Ā/B		2.7 V		8.2			
t _{pd}	A/B		3.3 V ± 0.3 V	0.8	7			
	G		2.7 V		7.8			
	G		3.3 V ± 0.3 V	0.8	6.5			

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Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

				SN74LVC157A							
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{cc}	$T_A = 25^{\circ}C$			–40 TO 85°C		–40 TO 125°C		UNIT
	((0011 01)		MIN	TYP	MAX	MIN	MAX	MIN	MAX	
			1.8 V ± 0.15 V	1	5.5	13.5	1	14	1	15.5	
	A or B		$2.5~V\pm0.2~V$	1	3.2	7.4	1	7.9	1	10	
	AUID		2.7 V	1	3.6	5.7	1	5.9	1	7.4	
			$3.3~V\pm0.3~V$	1	3	5	1	5.2	1	6.4	
	Ā/B	Y	1.8 V ± 0.15 V	1	6	15.5	1	16	1	17.5	ns
			$2.5~V\pm0.2~V$	1	3.7	9.6	1	10.1	1	12.2	
t _{pd}	A/D		2.7 V	1	4.1	7.9	1	8.1	1	10	
			$3.3~V\pm0.3~V$	1	3.4	6.6	1	6.8	1	8.4	
			1.8 V ± 0.15 V	1	5.9	13.5	1	14	1	15.5	
	G		2.5 V ± 0.2 V	1	3.5	9.3	1	9.8	1	11.9	
	G		2.7 V	1	3.9	7.6	1	7.8	1	9.3	
			3.3 V ± 0.3 V	1	3.3	6.3	1	6.5	1	7.9	
•			1.8 V ± 0.15 V					2		2.5	ns
t _{sk(o)}			$3.3~V\pm0.3~V$					1		1.5	119

Operating Characteristics

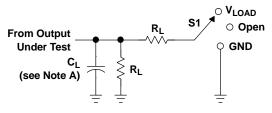
T_A = 25°C

	PARAMETER	TEST CONDITIONS	V _{CC}	TYP	UNIT
			1.8 V	14 ⁽¹⁾	
C_{pd}	Power dissipation capacitance	f = 10 MHz	2.5 V	15 ⁽¹⁾	pF
			3.3 V	16	

⁽¹⁾ On products compliant to MIL-PRF-38535, this parameter does not apply.

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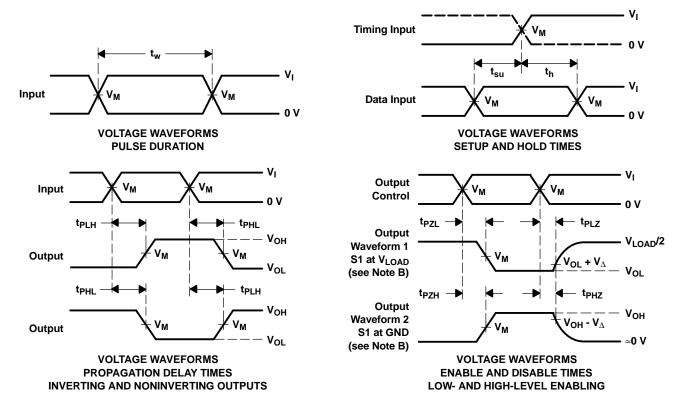
PARAMETER MEASUREMENT INFORMATION



TEST	S1
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	V _{LOAD}
t _{PHZ} /t _{PZH}	GND

LOAD CIRCUIT

.,	INPUTS		.,	.,		_	.,
V _{CC}	VI	t _r /t _f	V _M	V _{LOAD}	CL	R _L	$oldsymbol{V}_\Delta$
1.8 V ± 0.15 V	V _{CC}	≤2 ns	V _{CC} /2	2×V _{CC}	30 pF	1 k Ω	0.15 V
2.5 V \pm 0.2 V	V _{CC}	≤2 ns	V _{CC} /2	2×V _{CC}	30 pF	500 Ω	0.15 V
2.7 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V
3.3 V \pm 0.3 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_0 = 50 \ \Omega$.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en}.
- G. t_{PLH} and t_{PHL} are the same as t_{pd} .
- H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms



PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
5962-0050601Q2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
5962-0050601QEA	ACTIVE	CDIP	J	16	1	TBD	A42 SNPB	N / A for Pkg Type
5962-0050601QFA	ACTIVE	CFP	W	16	1	TBD	A42	N / A for Pkg Type
SN74LVC157AD	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC157ADBLE	OBSOLETE	SSOP	DB	16		TBD	Call TI	Call TI
SN74LVC157ADBR	ACTIVE	SSOP	DB	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC157ADBRG4	ACTIVE	SSOP	DB	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC157ADE4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC157ADG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC157ADR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC157ADRE4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC157ADRG4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC157ADT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC157ADTE4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC157ADTG4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC157ANSR	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC157ANSRE4	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC157ANSRG4	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC157APW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC157APWE4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC157APWG4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC157APWLE	OBSOLETE	TSSOP	PW	16		TBD	Call TI	Call TI
SN74LVC157APWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC157APWRE4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC157APWRG4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC157APWT	ACTIVE	TSSOP	PW	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC157APWTE4	ACTIVE	TSSOP	PW	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM



PACKAGE OPTION ADDENDUM

20-Mar-2008

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
SN74LVC157APWTG4	ACTIVE	TSSOP	PW	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC157AQDRG4Q1	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC157ARGYR	ACTIVE	QFN	RGY	16	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
SN74LVC157ARGYRG4	ACTIVE	QFN	RGY	16	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
SNJ54LVC157AFK	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
SNJ54LVC157AJ	ACTIVE	CDIP	J	16	1	TBD	A42 SNPB	N / A for Pkg Type
SNJ54LVC157AW	ACTIVE	CFP	W	16	1	TBD	A42	N / A for Pkg Type

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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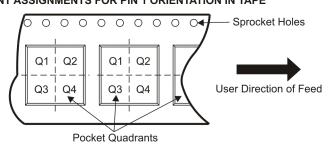
TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC157ADBR	SSOP	DB	16	2000	330.0	16.4	8.2	6.6	2.5	12.0	16.0	Q1
SN74LVC157ADR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
SN74LVC157ANSR	SO	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
SN74LVC157APWR	TSSOP	PW	16	2000	330.0	12.4	7.0	5.6	1.6	8.0	12.0	Q1
SN74LVC157ARGYR	QFN	RGY	16	1000	180.0	12.4	3.8	4.3	1.5	8.0	12.0	Q1





*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC157ADBR	SSOP	DB	16	2000	346.0	346.0	33.0
SN74LVC157ADR	SOIC	D	16	2500	333.2	345.9	28.6
SN74LVC157ANSR	SO	NS	16	2000	346.0	346.0	33.0
SN74LVC157APWR	TSSOP	PW	16	2000	346.0	346.0	29.0
SN74LVC157ARGYR	QFN	RGY	16	1000	190.5	212.7	31.8

PW (R-PDSO-G**)

14 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

FK (S-CQCC-N**)

28 TERMINAL SHOWN

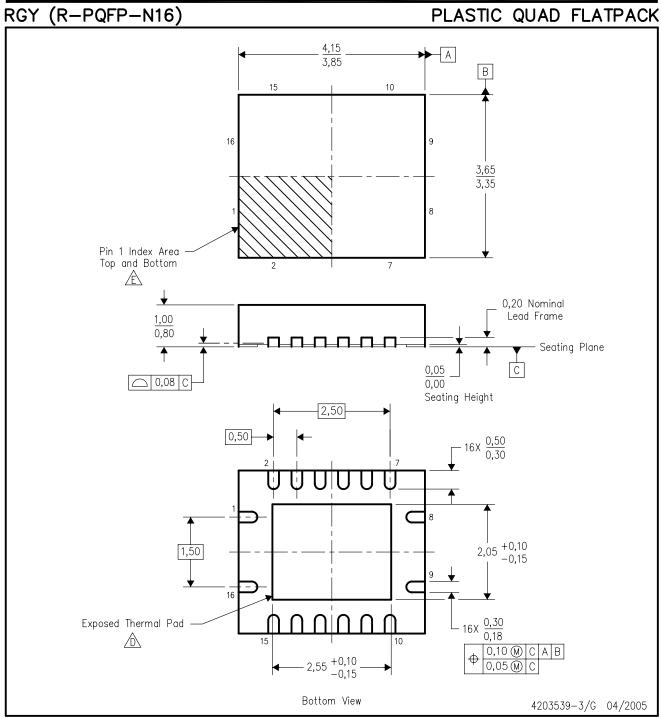
LEADLESS CERAMIC CHIP CARRIER



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a metal lid.
- D. The terminals are gold plated.
- E. Falls within JEDEC MS-004





NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No-Lead) package configuration.
- The package thermal pad must be soldered to the board for thermal and mechanical performance.
- Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
- F. Package complies to JEDEC MO-241 variation BB.



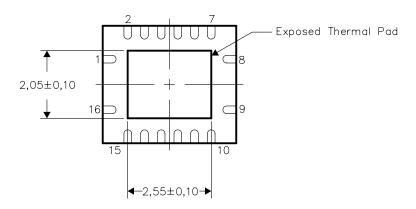
THERMAL PAD MECHANICAL DATA RGY (R-PQFP-N16)

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No—Lead (QFN) package and its advantages, refer to Application Report, Quad Flatpack No—Lead Logic Packages, Texas Instruments Literature No. SCBA017. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.

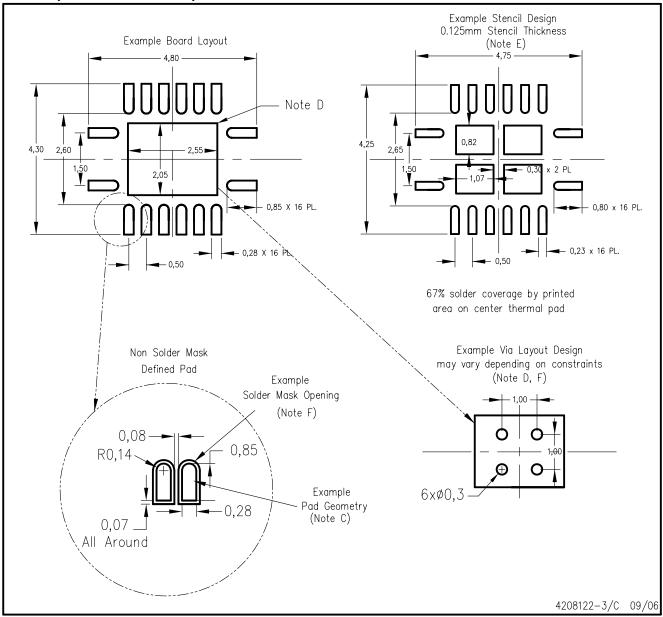


Bottom View

NOTE: All linear dimensions are in millimeters

Exposed Thermal Pad Dimensions

RGY (R-PQFP-N16)



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat—Pack Packages, Texas Instruments Literature No. SCBA017, SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com https://www.ti.com.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.



W (R-GDFP-F16)

CERAMIC DUAL FLATPACK



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only.
- E. Falls within MIL STD 1835 GDFP1-F16 and JEDEC MO-092AC



D (R-PDSO-G16)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.
- Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.
- E. Reference JEDEC MS-012 variation AC.



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